## NSN 5961-01-328-4616

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View Online at https://aerobasegroup.com/nsn/5961-01-328-4616 **Inclosure Material:** Metal and glass **Overall Length:** 4.2 millimeters **Terminal Length:** 19.0 millimeters **Overall Diameter:** 9.1 millimeters **Function For Which Designed:** Photodiode Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Mounting Method: Terminal Terminal Circle Diameter:** 5.1 millimeters **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 125.0 breakdown voltage, instantaneous **Current Rating Per Characteristic:** 5.00 nanoamperes emitter current, dc peak **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: